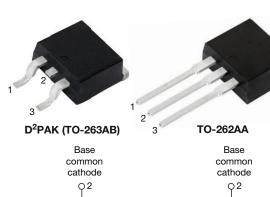
www.vishay.com

**Vishay Semiconductors** 

## High Performance Schottky Rectifier, 2 x 7.5 A



2  $\cap$ Common 👌 3 10 Anode cathode Anode

Anode cathode Anode VS-MBRB15..CT-M3

<u>ර</u> 2

Common 👌 3

10

VS-MBR15..CT-1-M3

PRIMARY CHARACT	PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 7.5 A				
V <sub>R</sub>	35 V, 45 V				
V <sub>F</sub> at I <sub>F</sub>	0.57 V				
I <sub>RM</sub> max.	15 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	7 mJ				
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Center tap TO-220 package
- · Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

The VS-MBR(B)15... center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	15	A		
V <sub>RRM</sub>		35/45	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	690	A		
V <sub>F</sub>	7.5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V		
TJ		-65 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRB1535CT-M3 VS-MBR1535CT-1-M3	VS-MBRB1545CT-M3 VS-MBR1545CT-1-M3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	35	45	N/
Maximum working peak reverse voltage	V <sub>RWM</sub>	30	40	V

Revision: 03-Nov-17 Document Number: 96403 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000





Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL		TEST CONDITIONS	VALUES	UNITS
Maximum average per leg		T <sub>C</sub> = 131 °C, rate		7.5	
forward current per device	I <sub>F(AV)</sub>	$T_{\rm C} = 131$ C, rate	u v <sub>R</sub>	15	
Maximum peak one cycle	<b>1</b>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	690	A
non-repetitive surge	IFSM	Surge applied at single phase, 60	rated load conditions halfwave, Hz	150	
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25 \ ^\circ C, \ I_{AS} =$	2 A, L = 3.5 mH	7	mJ
Repetitive avalanche current per leg	I <sub>AR</sub>	, ,	g linearly to zero in 1 μs d by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical	2	A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TES	T CONDITIONS	VALUES	UNITS
		15 A	T <sub>J</sub> = 25 °C	0.84	
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	7.5 A	T = 125 °C	0.57	V
		15 A		0.72	
	I (1)	T <sub>J</sub> = 25 °C	Deted DC veltage	0.1	A
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	Rated DC voltage	15	mA
Maximum junction capacitance	CT	V <sub>R</sub> = 5 V <sub>DC</sub> (test sign	al range 100 kHz to 1 MHz), 25 °C	400	pF
Typical series inductance	L <sub>S</sub>	Measured from top of	of terminal to mounting plane	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

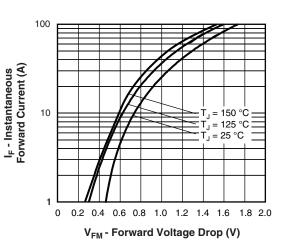
 $^{(1)}$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

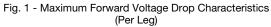
THERMAL - MECH	NICAL SP	PECIFICA	TIONS		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range		TJ		-65 to +150	°C
Maximum storage temperature range		T <sub>Stg</sub>		-65 to +175	C
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	3.0	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W
Maximum thermal resistanc junction to ambient	æ,	R <sub>thJA</sub>	DC operation	60	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf ⋅ cm
Mounting torque	maximum			12 (10)	(lbf ⋅ in)
Marking davias			Case style D <sup>2</sup> PAK (TO-263AB)	MBRB1	545CT
Marking device			Case style TO-262AA	MBR15	45CT-1



## VS-MBRB15..CT-M3, VS-MBR15..CT-1-M3

## **Vishay Semiconductors**





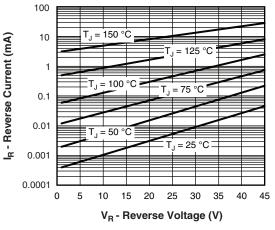


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

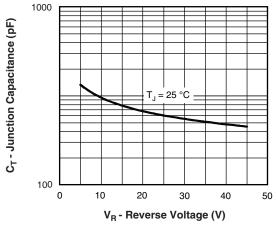


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

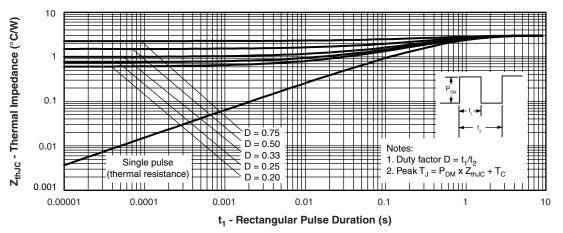
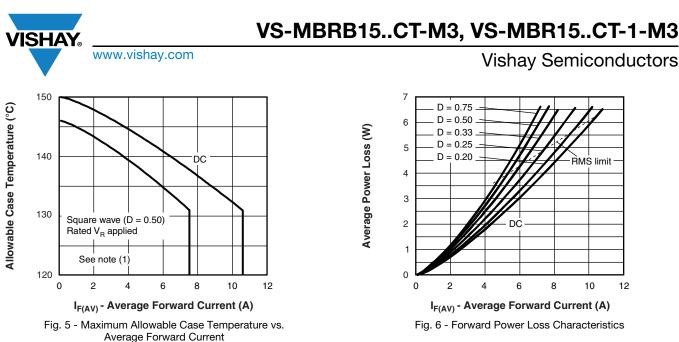


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

 Revision: 03-Nov-17
 3
 Document Number: 96403

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



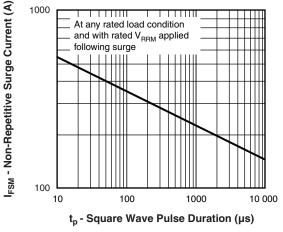
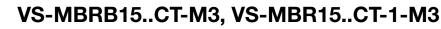


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

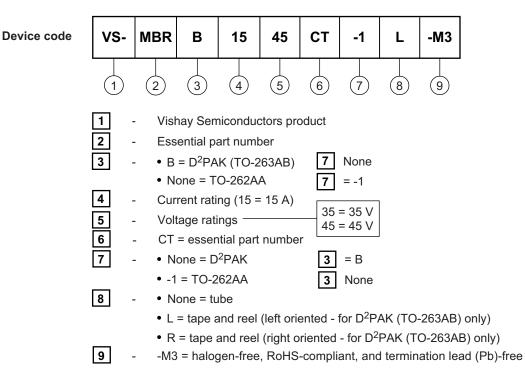
- (1)
- Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$



**Vishay Semiconductors** 

#### **ORDERING INFORMATION TABLE**

www.vishay.com



ORDERING INFORMATION					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-MBRB1535CT-M3	50	1000	Antistatic plastic tubes		
VS-MBRB1535CTR-M3	800	800	13" diameter reel		
VS-MBRB1535CTL-M3	800	800	13" diameter reel		
VS-MBR1535CT-1-M3	50	1000	Antistatic plastic tubes		
VS-MBRB1545CT-M3	50	1000	Antistatic plastic tubes		
VS-MBRB1545CTR-M3	800	800	13" diameter reel		
VS-MBRB1545CTL-M3	800	800	13" diameter reel		
VS-MBR1545CT-1-M3	50	1000	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS					
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164			
Dimensions	TO-262AA	www.vishay.com/doc?96165			
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			
SPICE model		www.vishay.com/doc?95294			

**Vishay Semiconductors** 

D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	NOTES	
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 13-Jul-17

1

Document Number: 96164

For technical questions within your region: DiodesAmericas@vishav.com, DiodesAsia@vishav.com, DiodesEurope@vishav.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



## **Outline Dimensions**



**Vishay Semiconductors** 

**TO-262AA** 

#### **DIMENSIONS** in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

CVMPOI	MILLIN	IETERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
 <sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis of the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

1



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

CUS06(TE85L,Q,M) MA4E2039 D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR30H100MFST1G MMBD301M3T5G PMAD1103-LF PMAD1108-LF RB160M-50TR RB520S-30 RB551V-30 DD350N18K DZ435N40K DZ600N16K BAS16E6433HTMA1 BAS 3010S-02LRH E6327 BAT 54-02LRH E6327 IDL02G65C5XUMA1 NSR05F40QNXT5G JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SBAT54CWT1G SK32A-LTP SK33A-TP SK34A-TP SK34B-TP SMD1200PL-TP ACDBN160-HF SS3003CH-TL-E STPS30S45CW PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBR1240MFST1G MBRB30H30CT-1G BAS28E6433HTMA1 BAS 70-02L E6327 HSB123JTR-E JANTX1N5712-1 VS-STPS40L45CW-N3 DD350N12K SB007-03C-TB-E SK110-LTP SK154-TP SK32A-TP SK33B-TP SK35A-TP